

Analyzing Intrinsic Superconducting Gap by Means of Measurement in $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_{8+x}$ superconductors

Hyun-Tak Kim (htkim@etri.re.kr)

Telecom. Basic Research Lab., ETRI, Taejeon 305-350, Korea

For the mechanism of high- T_c superconductivity in inhomogeneous $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_{8+x}$ superconductors, we demonstrate the intrinsic superconducting gap, Δ_i , and pairing symmetry by using a developed $\Delta = \Delta_i/\rho$, where Δ is the observed energy gap and $0 < \rho \leq 1$ is band filling. When $\rho=1$, $\Delta = \Delta_i \leq 10$ meV, measured at a node, is intrinsic. When $0 < \rho < 1$, Δ implies an averaging of Δ_i over the measurement region, which is the effect of measurement. From analysis's of conductance data, $b = 2\Delta_i/k_B T_c$ is less than 4 when $\rho=1$ and the density of state indicates s -wave symmetry. PACS number (s): 74.20.De, 74.50.+r

To reveal the mechanism of high- T_c superconductivity, it is essential to know the intrinsic superconducting energy gap and the intrinsic density of states (DOS). High- T_c superconductors are intrinsically spatially inhomogeneous; this is attributed to metal-insulator instability in which a half-filled metal lies in an unstable position in the local charge-density-wave potential.¹ The instability implies that the probability of one electron occupying a cubic unit is less than one. The implication indicates that a metallic system is separated into metal and insulator phases composed of cubic units with and without an electron, respectively, because the electron is not divided. Pan et al.^{2,3} has suggested as an alternate explanation that nonlinear screening of the ionic potential leads to strong inhomogeneous redistribution of the local hole density. The inhomogeneity was proven experimentally by scanning tunneling microscopy (STM).^{2,4,5,6} Both the local DOS and the energy gap are correlated spatially and vary on the surprisingly short length scale of about 14\AA .^{2,3} The transitions from superconducting state to a low temperature pseudogap state are spatially continuous and take place on a very local scale of 1-3 nm. The smallest characteristic size of superconducting islands is about 3 nm in diameter.^{4,5,6}

In the inhomogeneous superconductors, which are a mixture of an insulating phase and a metal phase (superconducting phase at low temperatures), the metallic (or insulating) characteristics are measured by the average of the two phases. The measured data are always composed of the effects of two phases, consequently, the intrinsic characteristics in the respective phases cannot be exactly measured. Therefore, since the discovery of high- T_c superconductors, problems such as the pseudogap, the intrinsic superconducting energy gap, the intrinsic DOS, and pairing symmetry remain unsolved although numerous experimental data and theories have been obtained and developed.

In this paper, we analyze the intrinsic superconducting gap and pairing symmetry by evaluating the local carrier density (or band filling), with tunneling spectra measured by intrinsic (or interlayer) tunneling spectroscopy (ITS), STM and photoemission spectroscopy for $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_{8+x}$ (Bi-2212) superconductors. ITS and

STM are very powerful tools for observing the intrinsic tunneling effect and for determining the most homogeneous spatial regions in a crystal, respectively.

The well-known BCS DOS of Eq. (2), which is applied to a homogeneous superconductor and defined at 0K, cannot be applied to experimental data measured in an inhomogeneous superconductor, which does not define k -space, so that the DOS must be converted into a DOS of a homogeneous superconductor. Here, metal phase on homogeneous superconductors imply that there is no charge difference between nearest neighbor sites, for example when there is one electron per atom in the electronic structure. When the carriers in the metal phase in the inhomogeneous superconductor are averaged over all atomic (or lattices) sites in the measurement region, it is possible to change the inhomogeneous superconductor into a homogeneous one with a carrier of an effective charge.^{7,8} Then, the effective charge of the carrier is given as a fractional charge, $e' = \rho e$, where $0 < \rho (= n/l) \leq 1$ is band filling, n is the number of carriers in the metal phase and l is the number of lattices.^{7,8} The number of bound charges, $n_b = l - n$, is bound in the insulating phase with a pseudogap; the total charges are conserved even in the inhomogeneous superconductor. The effective charge is justified only by means of measurement, that is, when not measured, the effective charge becomes the elementary true charge in the metal phase.

In the tunneling conductance ($\frac{dI}{dV}$), the observed energy gap, Δ , is given by

$$\Delta = eV_{bias} = \Delta_i/\rho, \quad (1)$$

from substituting e with e' . Δ increases as ρ decreases and is an averaged value of the intrinsic energy gap, Δ_i , over a measurement region. Δ_i is attributed to pairing of two electrons of true charge when $\rho=1$, is constant irrespective of the extent of ρ , and is determined by the minimum bias voltage.

The BCS DOS, tunneling conductance in the inhomogeneous superconductor, is given by

$$N_s(E)/N_n = \text{Re} \left(\frac{E}{\sqrt{E^2 - \Delta^2}} \right), \quad (2)$$

$$= \text{Re} \left(\frac{E}{\sqrt{E^2 - (\Delta_i/\rho)^2}} \right), \quad (3)$$

where Δ_i is Δ_s in an s -wave superconductor, $\Delta_s \cos(2\phi)$ in a d -wave superconductor, and E is an applied bias energy (or voltage). Considering the broadening effect, E is substituted with $E = E - i\Gamma$ where Γ is the broadening parameter.⁹ Equation (3) is valid in $|E| \geq \Delta$ in the s -symmetry case and is averaged by phase angle ϕ in the d -symmetry case. Eq. (3) has a coherence peak at the energy gap which increases with decreasing ρ , (Fig. 1); this, the unsolved problem^{10–12} in the tunneling conductance, is explained. It was experimentally demonstrated that analogous to Bi-2212, the energy gap in Bi-2201 monotonically increases with a decreasing hole concentration.¹³ Eq. (3) and the coherence peak energy when $\rho=1$ are regarded as the intrinsic DOS and Δ_i , respectively. The broadening parameter is always zero at 0 K when $\rho=1$. Eq. (3) and the peak energy when $0 < \rho < 1$ imply an averaging of the intrinsic DOS and Δ_i over the measurement region, which is the effect of measurement. This is because a tunneling spectrum observed by STM is the averaged spectrum over the Fermi surface.

When $|\frac{eV_{bias}}{\Delta}| < 1$ for a conductance curve, the DOS for s -wave pairing symmetry has flat bottom regions, while the DOS for d -wave symmetry has a V shape near zero-bias voltage and a peak width near the peak, (Fig. 1 (b)). This is not used for judging pairing symmetry in this research. When $|\frac{eV_{bias}}{\Delta}| > 1$, the DOS for s -wave symmetry has a much wider peak-width than the DOS for d -wave symmetry, (Fig. 1 (c)). Furthermore, even theoretical calculations for the superconductor-insulator-superconductor junctions in a d -wave superconductor showed a peak width of the coherence peak when $|\frac{eV_{bias}}{\Delta}| < 1$ rather than when $|\frac{eV_{bias}}{\Delta}| > 1$.^{14,15} The peak width plays a decisive role in judging pairing symmetry. When $|\frac{eV_{bias}}{\Delta}| = 1$ (or gap edge peak), the magnitude of the d -wave DOS, $N_s(0)/N_n \approx 5$, which is given by numerical calculations and is less than the values near the divergence in the s -wave DOS, (Fig. 1 (b) and see the caption), because the DOS is averaged over phase angles of $d_{x^2-y^2}$ symmetry. This indicates that quasiparticles are distributed inside the peak energy, but exist at the peak in the case of the s -wave. The true measured $N_s(E)/N_n$ cannot reach the calculated value 5 and may be less than 2 because there is no outside peak width above 2. $N_s(E)/N_n$ is an experimental coherence-peak height to a background value. Moreover, note that N_n in the normal state decreases as ρ decreases.^{7,8}

Bi-2212 superconductors have been judged as d -wave superconductors by analysis of conductance curves near zero-bias voltage.^{16,17} However, this analysis contains a fatal error in which a pseudogap in the data, in which the effect of the two phases was merged, was not removed. For a tunneling conductance measured for Bi-2212 thin films, a low temperature pseudogap (LTPG) has no co-

herence peak and gap widths of 30-35 meV corresponding to nearly the superconducting energy gap of optimal doped crystals.¹⁸ Similar analysis's were given by several groups.^{3,12,19} This indicates that two DOS curves overlap when $|\frac{eV_{bias}}{\Delta}| < 1$, and that the coherence peak is only the superconducting energy-gap peak without LTPG. Thus, we can judge pairing symmetry through observations of the magnitude and shape of the coherence peak for a conductance without the dip-hump structure from experimental data measured at a local superconducting region of $\rho \approx 1$ and $\Gamma=0$, although the dip-hump structure is a universal feature of high- T_c superconductors.^{4,13} It has been suggested that the dip-hump structure is a high-energy pseudogap with a V -shape near zero-bias voltage.^{20,21}

Pan et al.² measured the well-shaped tunneling-conductance curve 5 with a clear coherence peak at $\Delta \approx 25$ meV, using STM, as shown in Fig. 3 (c) of their paper. On the basis of their analysis, curve 5, which is observed at a larger ρ value than for other curve numbers, resembled the spectra behavior of an oxygen over-doped Bi-2212 crystal. This implies that the intrinsic DOS curve is similar to the curve measured in over-doped crystals. Similar analysis's were given by several groups as well.^{4–6} Hasegawa et al.²² and Kitazawa et al.²³ observed tunneling conductances for single crystals of Bi-2212 in atomic resolution, using STM. The conductances revealed clear coherence peaks at about $\Delta \approx 22$ meV²² and at about $\Delta \approx 17$ meV in Fig. 6 of Kitazawa et al.'s paper²³, with a peak width occurring when $|\frac{eV_{bias}}{\Delta}| > 1$, as suggested in previous explanations, and flat bottom regions around $V_{bias}=0$. The broadening parameter Γ is less than 1%. They suggested that the observation is favored by the s -wave pairing mechanism. Moreover, analysis results for YBCO are the same as those of Bi-2212.²² Miyakawa et al.^{10,11} observed energy gaps, $\Delta \approx 15$ -20 meV, for over-doped Bi-2212 crystals, using STM. Fig. 1 of Zasadzinski et al.'s paper¹⁷ showed that, when $|\frac{eV_{bias}}{\Delta}| > 1$, peak widths of coherence peaks for experimental data are much wider than peak widths of d -wave fitting data for an optimally doped Bi-2212 crystal and an over-doped Bi-2212 crystal. This indicates that pairing symmetry of Bi-2212 is s -wave, according to the suggestion mentioned in a previous section. Cren et al.¹⁷ observed the unchanged gap widths within given superconducting regions (or a given ρ). This indicates that Δ_i is constant, as suggested in Eq. (1).

Figure 2 in Krasnov et al.'s paper²⁴, Fig. 2 (a) in Suzuki et al.'s paper²⁵, and Figs. 2 and 3 in Heim et al.'s paper²⁶ showed clear tunneling conductances, which were measured by ITS, without the dip-hump structure. The conductances exhibited s -wave DOS characteristics through observations of the coherence peak for an under-doped Bi-2212 crystal²⁴ and a slightly over-doped Bi-2212 crystal^{25,26}. In particular, $N_s(E)/N_n$ is larger than 5. Using ITS for high quality Bi-2212 crystals and films, the energy gaps were measured as $2\Delta \approx 25$ meV by Lee

and Iguchi²⁷, inter-branch value, $2\Delta \approx 25$ meV, obtained from I-V curves by Doh et al.²⁸, and $2\Delta \approx 16$ meV by Latyshev et al.²⁰.

On the other hand, the size of the X-ray beam for photoemission spectroscopy (PES) cannot be reduced to less than 30\AA , so that experimental data have much larger insulating effect than data measured by STM. However, an angle resolved PES gives information on DOS's at a node and a non-node. Moreover, when PES data are judged for pairing symmetry, only the magnitude and shape of the coherence peak should be analyzed. The result of analysis is consistent with the previous tunneling analysis. As a good example, the bottom figures in Fig. 3 of Margaritondo et al.'s paper²⁹ showed the same behavior as data measured by STM.

Although the gap anisotropy has been suggested as evidence of *d*-wave symmetry³⁰, instead it indicates, according to Eq. (1), that $\rho_{\Gamma-Y}$ for the small gap at a node $\Gamma - Y$ is larger than $\rho_{\bar{M}}$ for the large gap at \bar{M} of $(\pi, 0)$. The large $\rho_{\Gamma-Y} (= \rho_{\bar{M}} + \frac{n_b}{T} \approx 1)$ is because bound charges, n_b , become carriers when the hump structure disappears at the node $\Gamma - Y$; the transition from the insulator with the pseudogap to the metal occurs. Fig. 1 of Shen's paper³⁰ showed the absence of the hump at the node, which indicates that the pseudogap has *d*-wave symmetry. The gap anisotropy is the effect of measurement and the gap anisotropy of Δ_i cannot be measured for inhomogeneous superconductors. A clear coherence peak at the node with $\rho \approx 1$ was observed with a small gap, $\Delta \approx 10$ meV,^{31,32,33} and the small gap is much closer to Δ_i than the large gap at \bar{M} ; $\Delta_i \leq 10$ meV. Note that the energy gap observed by STM is larger than the gap observed at the node by PES because of an average of the small gap at a node and the large gap at the non-node, and that the dip-hump structure in tunneling spectra comes from the non-node \bar{M} . Furthermore, when the hump structure disappears at nodes and non-nodes, the gaps become isotropic due to the same ρ . The isotropic gaps in the structures without humps were experimentally observed, although the observation depended on the properties of the cleaned sample surface;³⁴ the metal phase with $\rho = 1$ at the sample surface is unstable because of the metal-insulator instability¹. A result of electronic Raman scattering also showed the isotropic gaps measured in an overdoped Bi-2212 crystal.³⁵

The strong spin-fermion model³⁶ for a homogeneous *d*-wave superconductor of $\rho = 1$ proposed both the dip-hump structure and the broad coherence peak with a logarithmic singularity when $|\frac{eV_{bias}}{\Delta}| > 1$. The broad coherence peak and the dip-hump structure in experimental data could be suggested as evidence of the strong spin-fermion coupling for a *d*-wave superconductor. However, according to the model, though the coherence peak and the dip-hump structure should disappear at the same time at the node $\Gamma - Y$, but only the dip-hump structure disappeared³⁰, while the coherence peak remained clear^{31,32,33}. This indicates that the model does not ex-

plain the experimental data.

Lang et al.'s recent research⁶ on local superconductivity by quasiparticle scattering resonances at Ni impurity atoms and a STM for a Bi-2212, can be analyzed on the basis of Eq. (1). First, several observed energy gaps, $18\text{meV} \leq \Delta \leq 50\text{meV}$, indicate that local superconducting regions with different ρ measurement values exist, which suggests that the Bi-2212 is a granular (or inhomogeneous) superconductor. This agrees with their analysis. Second, the maximum number of Ni scattering resonances at $\Delta \approx 35\text{meV}$ indicates that local superconducting regions with $\Delta \approx 35\text{meV}$ are much more than those with other gaps. Third, the observation of the strongest Ni resonance peak near $\Delta \approx 18\text{meV}$ ³⁷ indicates that ρ is the largest, which suggests that $\Delta \approx 18\text{meV}$ tends to the intrinsic gap in the scope of the measurements. Finally, the absence of an observable Ni resonances in regions with $\Delta > 50$ meV may indicate that the regions are in the insulating phase with the non-quasiparticles, n_b , which do not interact with Ni impurity spins, which corresponds to their final hypothesis. Furthermore, the several observed gaps are the effect of measurement.

In conclusion, in the inhomogeneous superconductor of $0 < \rho < 1$, the measured energy gap does not correlate with T_c measured macroscopically because the measured values are the effect of measurement. However, in the homogeneous superconductor of $\rho = 1$ which is the metal phase (or superconducting phase at low temperatures) in the inhomogeneous superconductor, the intrinsic gap is proportional to the intrinsic critical temperature of the maximum measured value, $T_{c,max}$; $b = 2\Delta_i/k_B T_{c,max}$. When $T_{c,max} \approx 93$ K observed at an optimal doping and $\Delta_i \approx 10$ meV observed at the node are used, the coupling constant, b , is less than 4.0. Here, note that T_c has the maximum value irrespective of the extent of the metal phase with $\rho=1$ because of the largest DOS^{7,8}, and that $T_{c,max}$ can be measured only at a node with $\rho \approx 1$, such as Δ_i . The intrinsic DOS showed *s*-wave symmetry. Thus, high- T_c superconductivity can be explained within the context of the BCS theory.

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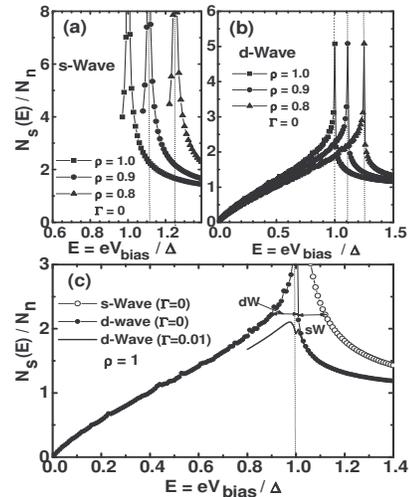


FIG. 1. (a) Band filling, ρ , dependence of the s -wave DOS of Eq. (3). $\frac{N_s(E)}{N_n} = 0$ is assumed in $|\frac{E=eV_{bias}}{\Delta}| < 1$. Peak curves when $|\frac{eV_{bias}}{\Delta}| < 1$ are just given for a comparison to curves when $|\frac{eV_{bias}}{\Delta}| > 1$. (b) Band filling dependence of the d -wave DOS of Eq. (3). The DOS's were precisely calculated from $\frac{N_s(E)}{N_n} = \frac{1}{2\pi} \int \frac{N_s(E, \phi)}{N_n} d\phi$ with $\Delta = \Delta_s \cos(2\phi)$ and $\Gamma = 0$ by numerical analysis not using complete elliptic integrals. Divergences in calculations were ignored because the divergences have no derivative width ($d\phi = 0$). (c) Comparison of s and d -wave DOS's with $\Gamma = 0$ and $\Gamma = 0.01$. sW denotes the s -wave width and dW represents the d -wave width.